

TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

## TC74VHC174F, TC74VHC174FN, TC74VHC174FT

### Hex D-Type Flip Flop with Clear

The TC74VHC174 is an advanced high speed CMOS HEX D-TYPE FLIP FLOP fabricated with silicon gate C<sup>2</sup>MOS technology.

It achieves the high speed operation similar to equivalent Bipolar Schottky TTL while maintaining the CMOS low power dissipation.

Information signals applied to D inputs are transferred to the Q output on the positive going edge of the clock pulse.

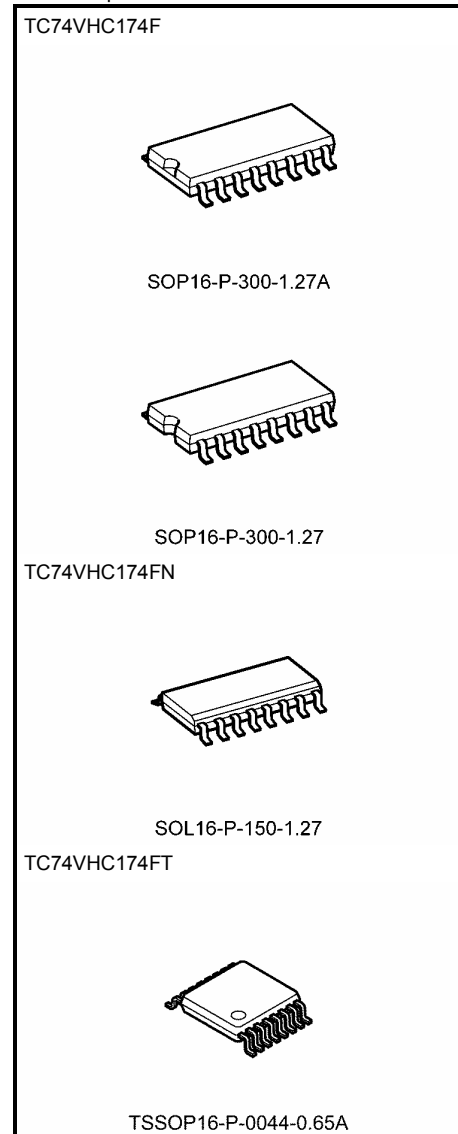
When the  $\overline{\text{CLR}}$  input is held low, the Q output are in the low logic level independent of the other inputs.

An input protection circuit ensures that 0 to 5.5 V can be applied to the input pins without regard to the supply voltage. This device can be used to interface 5 to 3 V systems and two supply systems such as battery back up. This circuit prevents device destruction due to mismatched supply and input voltages.

### Features

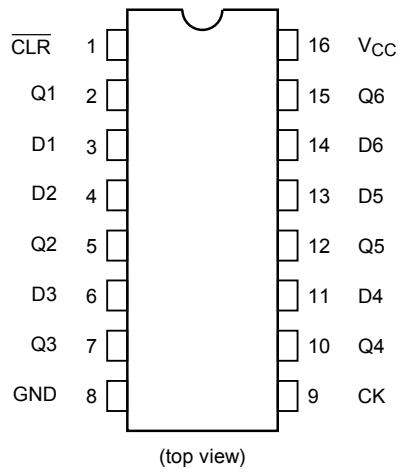
- High speed:  $f_{\text{max}} = 150 \text{ MHz (typ.)}$  at  $V_{\text{CC}} = 5 \text{ V}$
- Low power dissipation:  $I_{\text{CC}} = 4 \mu\text{A (max)}$  at  $T_a = 25^\circ\text{C}$
- High noise immunity:  $V_{\text{NIH}} = V_{\text{NIL}} = 28\% V_{\text{CC}}$  (min)
- Power down protection is provided on all inputs.
- Balanced propagation delays:  $t_{\text{pLH}} \approx t_{\text{pHL}}$
- Wide operating voltage range:  $V_{\text{CC (opr)}} = 2 \text{ to } 5.5 \text{ V}$
- Low noise:  $V_{\text{OLP}} = 0.8 \text{ V (max)}$
- Pin and function compatible with 74ALS174

Note: xxxFN (JEDEC SOP) is not available in Japan.

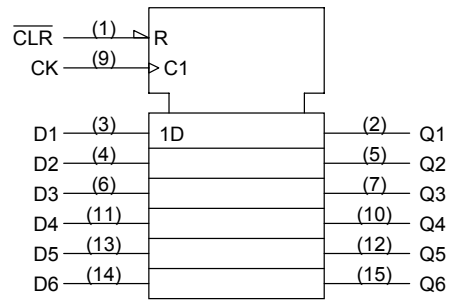


Weight	
SOP16-P-300-1.27A	: 0.18 g (typ.)
SOP16-P-300-1.27	: 0.18 g (typ.)
SOL16-P-150-1.27	: 0.13 g (typ.)
TSSOP16-P-0044-0.65A	: 0.06 g (typ.)

## Pin Assignment



## IEC Logic Symbol

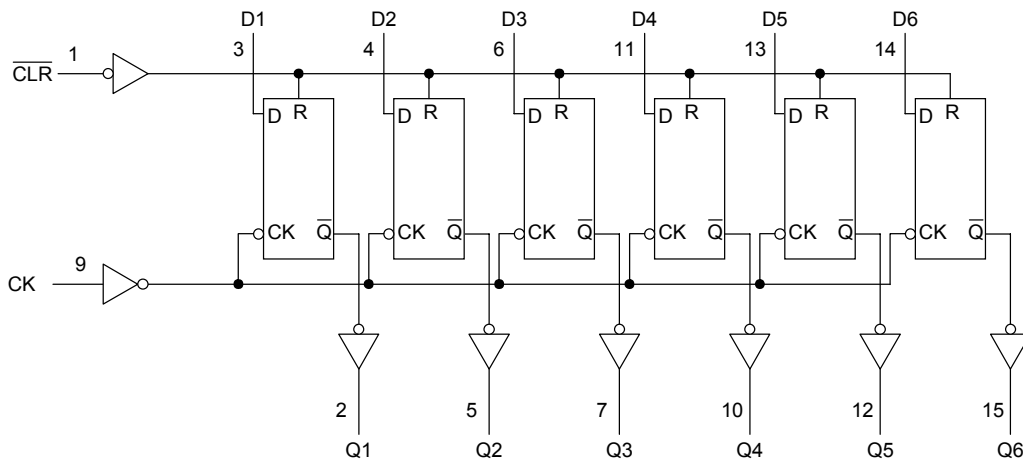


## Truth Table

Inputs			Output	Function
$\overline{\text{CLR}}$	D	CK	Q	
L	X	X	L	Clear
H	L	$\uparrow$	L	—
H	H	$\uparrow$	H	—
H	X	$\downarrow$	$Q_n$	No Change

X: Don't care

## System Diagram



## Absolute Maximum Ratings (Note)

Characteristics	Symbol	Rating	Unit
Supply voltage range	$V_{CC}$	-0.5 to 7.0	V
DC input voltage	$V_{IN}$	-0.5 to 7.0	V
DC output voltage	$V_{OUT}$	-0.5 to $V_{CC} + 0.5$	V
Input diode current	$I_{IK}$	-20	mA
Output diode current	$I_{OK}$	$\pm 20$	mA
DC output current	$I_{OUT}$	$\pm 25$	mA
DC $V_{CC}$ /ground current	$I_{CC}$	$\pm 50$	mA
Power dissipation	$P_D$	180	mW
Storage temperature	$T_{stg}$	-65 to 150	$^{\circ}C$

Note: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

## Recommended Operating Conditions (Note)

Characteristics	Symbol	Rating	Unit
Supply voltage	$V_{CC}$	2.0 to 5.5	V
Input voltage	$V_{IN}$	0 to 5.5	V
Output voltage	$V_{OUT}$	0 to $V_{CC}$	V
Operating temperature	$T_{opr}$	-40 to 85	$^{\circ}C$
Input rise and fall time	dt/dv	0 to 100 ( $V_{CC} = 3.3 \pm 0.3$ V) 0 to 20 ( $V_{CC} = 5 \pm 0.5$ V)	ns/V

Note: The recommended operating conditions are required to ensure the normal operation of the device. Unused inputs must be tied to either VCC or GND.

## Electrical Characteristics

### DC Characteristics

Characteristics	Symbol	Test Condition		Ta = 25°C			Ta = -40 to 85°C		Unit	
				V <sub>CC</sub> (V)	Min	Typ.	Max	Min		Max
High-level input voltage	V <sub>IH</sub>	—		2.0 3.0 to 5.5	1.50 V <sub>CC</sub> × 0.7	— —	— —	1.50 V <sub>CC</sub> × 0.7	— —	V
Low-level input voltage	V <sub>IL</sub>	—		2.0 3.0 to 5.5	— —	— —	0.50 V <sub>CC</sub> × 0.3	— —	0.50 V <sub>CC</sub> × 0.3	V
High-level output voltage	V <sub>OH</sub>	V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>	I <sub>OH</sub> = -50 μA	2.0 3.0 4.5	1.9 2.9 4.4	2.0 3.0 4.5	— — —	1.9 2.9 4.4	— — —	V
			I <sub>OH</sub> = -4 mA	3.0	2.58	—	—	2.48	—	
			I <sub>OH</sub> = -8 mA	4.5	3.94	—	—	3.80	—	
Low-level output voltage	V <sub>OL</sub>	V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>	I <sub>OL</sub> = 50 μA	2.0 3.0 4.5	— — —	0.0 0.0 0.0	0.1 0.1 0.1	— — —	0.1 0.1 0.1	V
			I <sub>OL</sub> = 4 mA	3.0	—	—	0.36	—	0.44	
			I <sub>OL</sub> = 8 mA	4.5	—	—	0.36	—	0.44	
Input leakage current	I <sub>IN</sub>	V <sub>IN</sub> = 5.5 V or GND		0 to 5.5	—	—	±0.1	—	±1.0	μA
Quiescent supply current	I <sub>CC</sub>	V <sub>IN</sub> = V <sub>CC</sub> or GND		5.5	—	—	4.0	—	40.0	μA

### Timing Requirements (input: t<sub>r</sub> = t<sub>f</sub> = 3 ns)

Characteristics	Symbol	Test Condition		Ta = 25°C		Ta = -40 to 85°C	Unit	
				V <sub>CC</sub> (V)	Typ.	Limit		Limit
Minimum pulse width (CK)	t <sub>w</sub> (L)	—		3.3 ± 0.3	—	5.0	5.0	ns
	t <sub>w</sub> (H)	—		5.0 ± 0.5	—	5.0	5.0	
Minimum pulse width ( $\overline{\text{CLR}}$ )	t <sub>w</sub> (L)	—		3.3 ± 0.3 5.0 ± 0.5	— —	5.0 5.0	5.0 5.0	ns
Minimum set-up time	t <sub>s</sub>	—		3.3 ± 0.3	—	5.0	6.0	ns
		—		5.0 ± 0.5	—	4.5	4.5	
Minimum hold time	t <sub>h</sub>	—		3.3 ± 0.3	—	0.0	0.0	ns
		—		5.0 ± 0.5	—	0.5	0.5	
Minimum removal time ( $\overline{\text{CLR}}$ )	t <sub>rem</sub>	—		3.3 ± 0.3	—	3.0	3.0	ns
		—		5.0 ± 0.5	—	2.5	2.5	

## AC Characteristics (input: $t_r = t_f = 3$ ns)

Characteristics	Symbol	Test Condition	Ta = 25°C			Ta = -40 to 85°C		Unit		
			V <sub>CC</sub> (V)	C <sub>L</sub> (pF)	Min	Typ.	Max		Min	Max
Propagation delay time (CK-Q)	t <sub>pLH</sub>	—	3.3 ± 0.3	15	—	7.2	11.0	1.0	13.0	ns
				50	—	9.7	14.5	1.0	16.5	
	5.0 ± 0.5		15	—	4.9	7.2	1.0	8.5		
			50	—	6.4	9.2	1.0	10.5		
Propagation delay time ( $\overline{\text{CLR}}-Q$ )	t <sub>pHL</sub>	—	3.3 ± 0.3	15	—	7.4	11.4	1.0	13.5	ns
				50	—	9.9	14.9	1.0	17.0	
			5.0 ± 0.5	15	—	5.1	7.6	1.0	9.0	
				50	—	6.6	9.6	1.0	11.0	
Maximum clock frequency	f <sub>max</sub>	—	3.3 ± 0.3	15	95	150	—	80	—	MHz
				50	55	85	—	50	—	
			5.0 ± 0.5	15	130	175	—	110	—	
				50	90	120	—	80	—	
Output to output skew	t <sub>osLH</sub>	(Note 1)	3.3 ± 0.3	50	—	—	1.5	—	1.5	ns
	t <sub>osHL</sub>		5.5 ± 0.5	50	—	—	1.0	—	1.0	
Input capacitance	C <sub>IN</sub>	—	—	—	4	10	—	10	pF	
Power dissipation capacitance	C <sub>PD</sub>	(Note 2)	—	—	29	—	—	—	pF	

Note 1: Parameter guaranteed by design.

$$t_{osLH} = |t_{pLHm} - t_{pLHn}|, t_{osHL} = |t_{pHLm} - t_{pHLn}|$$

Note 2: C<sub>PD</sub> is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation:

$$I_{CC(opr)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}/6 \text{ (per F/F)}$$

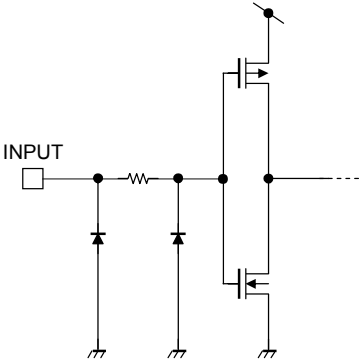
And the total C<sub>PD</sub> when n pcs. of flip flop operate can be gained by the following equation:

$$C_{PD} \text{ (total)} = 19 + 10 \cdot n$$

## Noise Characteristics (input: $t_r = t_f = 3$ ns)

Characteristics	Symbol	Test Condition	Ta = 25°C			Unit
			V <sub>CC</sub> (V)	Typ.	Max	
Quiet output maximum dynamic V <sub>OL</sub>	V <sub>OLP</sub>	C <sub>L</sub> = 50 pF	5.0	0.4	0.8	V
Quiet output minimum dynamic V <sub>OL</sub>	V <sub>OLV</sub>	C <sub>L</sub> = 50 pF	5.0	-0.4	-0.8	V
Minimum high level dynamic input voltage	V <sub>IHD</sub>	C <sub>L</sub> = 50 pF	5.0	—	3.5	V
Maximum low level dynamic input voltage	V <sub>ILD</sub>	C <sub>L</sub> = 50 pF	5.0	—	1.5	V

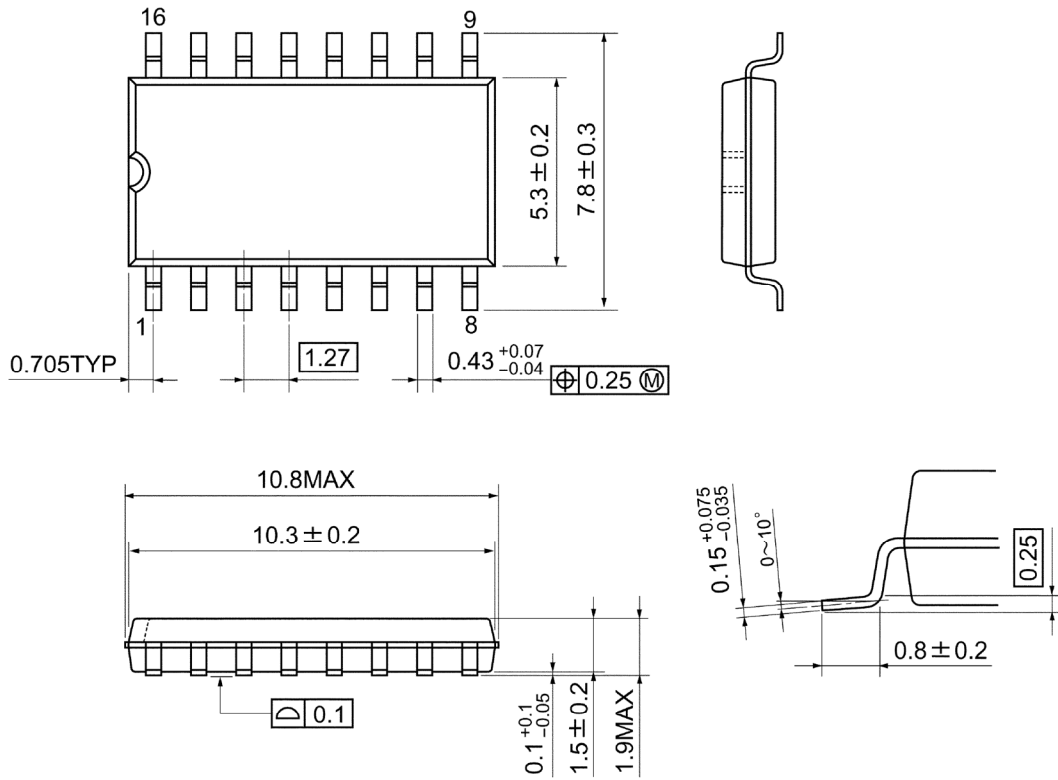
**Input Equivalent Circuit**



## Package Dimensions

SOP16-P-300-1.27A

Unit: mm

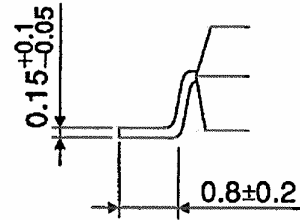
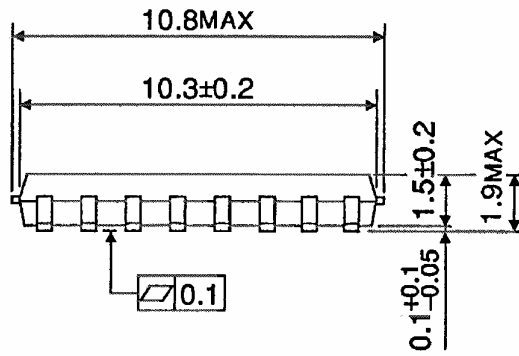
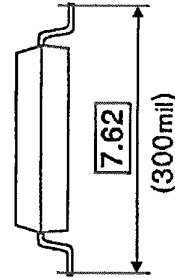
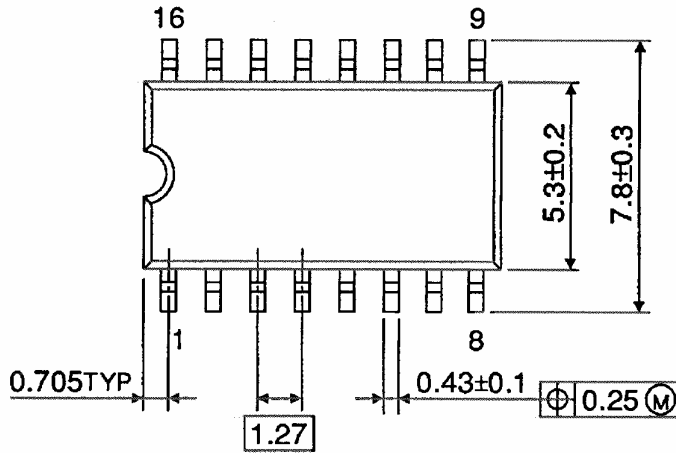


Weight: 0.18 g (typ.)

## Package Dimensions

SOP16-P-300-1.27

Unit : mm



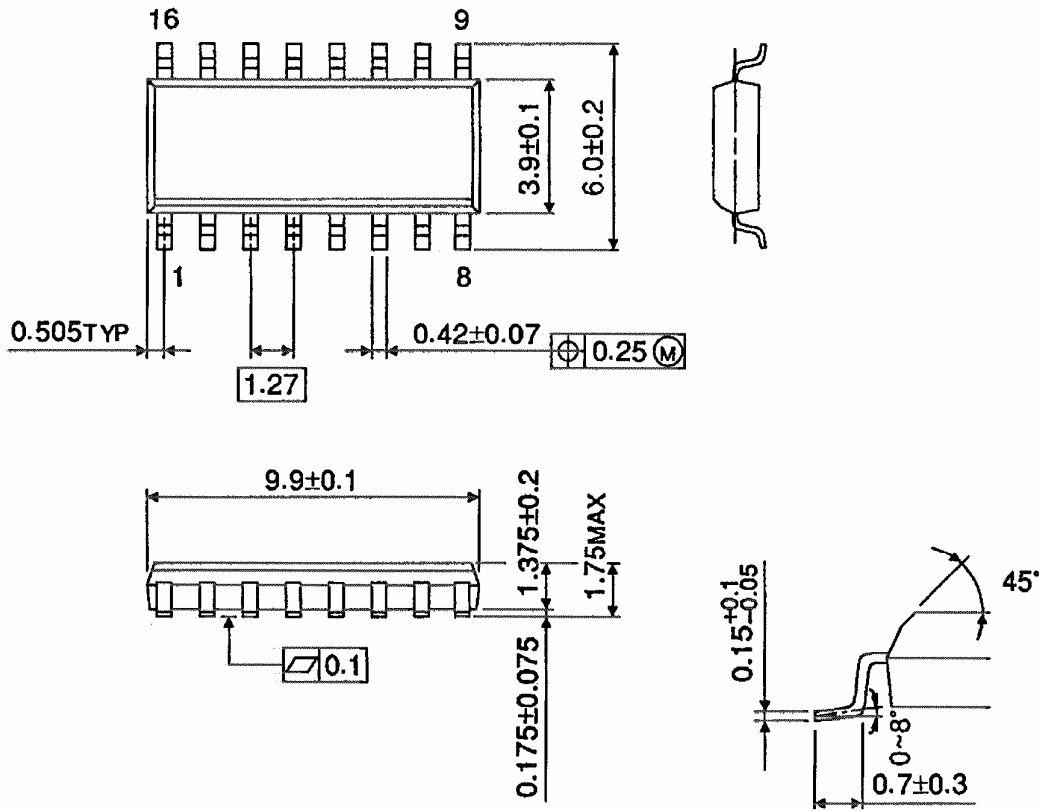
Weight: 0.18 g (typ.)



Package Dimensions (Note)

SOL16-P-150-1.27

Unit : mm



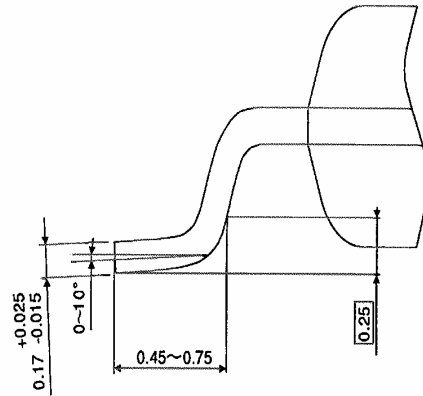
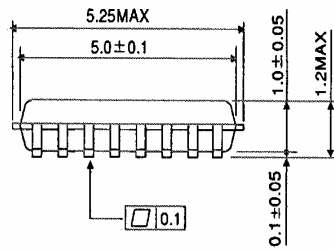
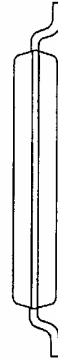
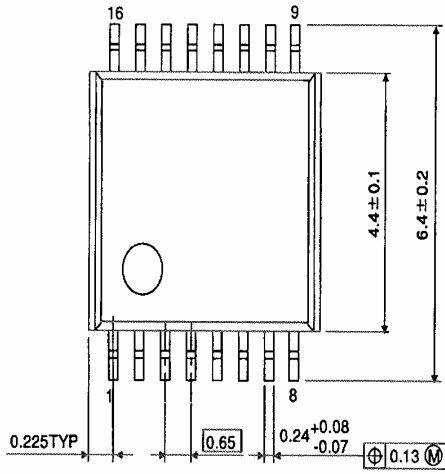
Note: This package is not available in Japan.

Weight: 0.13 g (typ.)

Package Dimensions

TSSOP16-P-0044-0.65

Unit : mm



Weight: 0.06 g (typ.)

**Note: Lead (Pb)-Free Packages****SOP16-P-300-1.27A SOL16-P-150-1.27 TSSOP16-P-0044-0.65A****RESTRICTIONS ON PRODUCT USE**

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